Unit: mm

TOSHIBA Field Effect Transistor Silicon N-Channel MOS Type (U-MOS V-H)

TPCC8002-H

High-Efficiency DC-DC Converter Applications Notebook PC Applications Portable Equipment Applications

- · Small footprint due to a small and thin package
- · High-speed switching
- Small gate charge: Q_{SW} = 7.1 nC (typ.)
- Low drain-source ON-resistance:

 $R_{DS (ON)} = 7.6 \text{ m}\Omega \text{ (typ.)} \text{ (} V_{GS} = 4.5 \text{ V)}$

- High forward transfer admittance: $|Y_{fs}| = 65 \text{ S (typ.)}$
- Low leakage current: $I_{DSS} = 10 \mu A (max) (V_{DS} = 30 V)$
- Enhancement mode: $V_{th} = 1.5$ to 2.5 V ($V_{DS} = 10$ V, $I_D = 1$ mA)

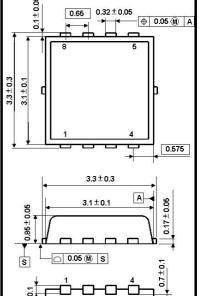
Absolute Maximum Ratings (Ta = 25°C)

Characte	eristic	Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Drain-gate voltage (F	l _{GS} = 20 kΩ)	V_{DGR}	30	V
Gate-source voltage		V_{GSS}	±20	V
Drain current	DC (Note 1)	ID	22	Α
Diain current	Pulsed (Note 1)	I _{DP}	66	A
Drain power dissipati	on (Tc = 25°C)	P_{D}	30	W
Drain power dissipation	on $(t = 10 s)$ (Note 2a)	P_{D}	1.9	W
Drain power dissipati	on (t = 10 s) (Note 2b)	P _D	0.7	W
Single-pulse avalance	he energy (Note 3)	E _{AS}	126	mJ
Avalanche current		I _{AR}	22	Α
Repetitive avalanche (To	energy c = 25°C) (Note 4)	E _{AR}	2.1	mJ
Channel temperature		T _{ch}	150	°C
Storage temperature	range	T _{stg}	-55 to 150	°C

Note: For Notes 1 to 4, refer to the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.02 g (typ.)

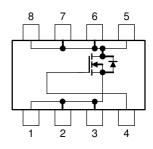
5,6,7,8:DRAIN

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Circuit Configuration

1,2,3:SOURCE 4:GATE

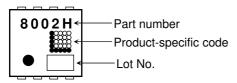
2-3X1A



Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to case (Tc = 25°C)	R _{th (ch-c)}	4.2	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2a)	R _{th (ch-a)}	66	°C/W
Thermal resistance, channel to ambient $(t = 10 \text{ s})$ (Note 2b)	R _{th (ch-a)}	180	°C/W

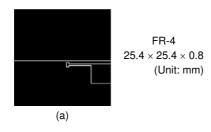
Marking (Note 5)

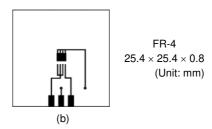


Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a)

(b) Device mounted on a glass-epoxy board (b)

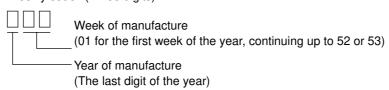




Note 3: $V_{DD} = 24~V,~T_{Ch} = 25^{\circ}C$ (initial), $L = 200~\mu H,~R_G = 25~\Omega,~I_{AR} = 22~A$

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

Note 5: * Weekly code: (Three digits)



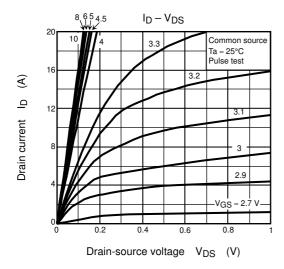
Electrical Characteristics (Ta = 25°C)

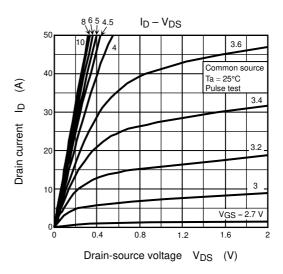
Ch	aracteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±100	nA
Drain cutoff curre	nt	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V		_	10	μА
Drain agurag bro	okdowa voltago	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	30	_	_	V
Drain-source breakdown voltage		V (BR) DSX	$I_D = 10 \text{ mA}, V_{GS} = -20 \text{ V}$	15	_	_	v
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$	1.5	_	2.5	٧
Drain-source ON	resistance	Bro (ON)	$V_{GS} = 4.5 \text{ V}, I_D = 11 \text{ A}$	_	7.6	10.6	mΩ
Diain-source ON	resistance	nds (ON)	V _{GS} = 10 V, I _D = 11 A	— — 10 30 — — 15 — — 1.5 — 2.5 — 7.6 10.6 — 5.5 8.3 33 65 — — 1900 2500 — 110 170 — 400 — — 3.2 4.8 — 3.9 —	11122		
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 11 A	33	65	_	S
Input capacitance)	C _{iss}		_	1900	2500	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	110	170	pF
Output capacitance		Coss		_	400	_	
Gate resistance		rg	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 5 \text{ MHz}$	_	3.2	4.8	Ω
Output capacitance Gate resistance Rise time Turn-on time Fall time Turn-off time	Rise time	t _r	10 V □ In = 11 A	_	3.9	_	
	t _{on}	VGS OV COUT	_	11.7	_		
Switching time	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	_	- ns				
	Turn-off time	t _{off}	55	_	39	_	
Total gate charge	otal gate charge		$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 22 \text{ A}$	_	27	_	
(gate-source plus	gate-drain)	Qg	$V_{DD} \approx 24 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 22 \text{ A}$	_			
Gate-source charge 1		Q _{gs1}		_	6.8	_	nC
Gate-drain ("Miller") charge		Q _{gd}	$V_{DD} \approx 24 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 22 \text{ A}$	_	4.3	_	
Gate switch char	ge	Q _{SW}		_	7.1	_	

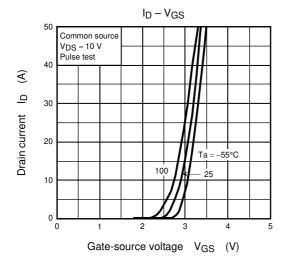
Source-Drain Ratings and Characteristics (Ta = 25°C)

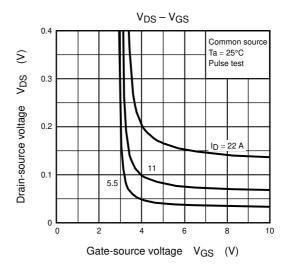
Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit	
Drain reverse current	Pulse	(Note 1)	I _{DRP}	_	_	_	66	Α
Forward voltage (diode)			V_{DSF}	$I_{DR} = 22 \text{ A}, V_{GS} = 0 \text{ V}$		_	-1.2	V

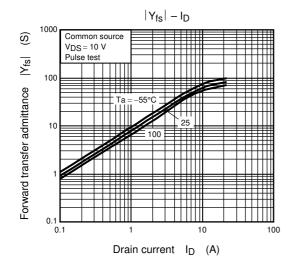
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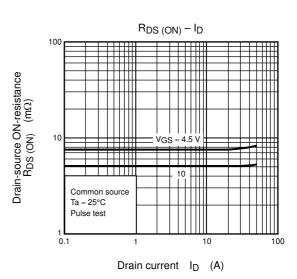




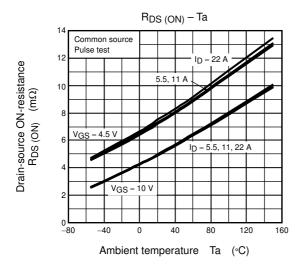


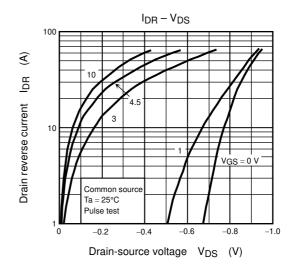


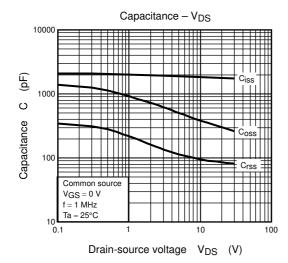


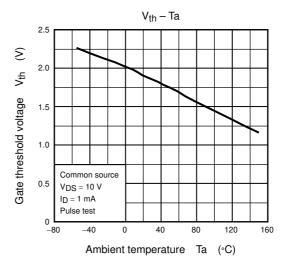


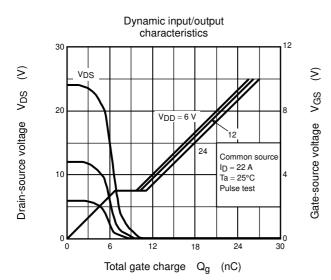
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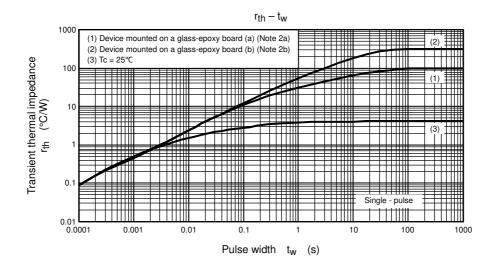


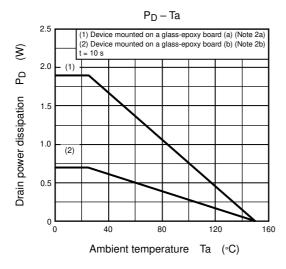


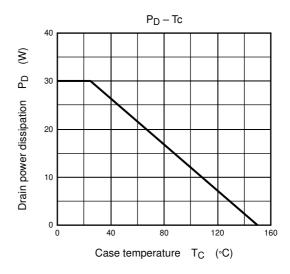


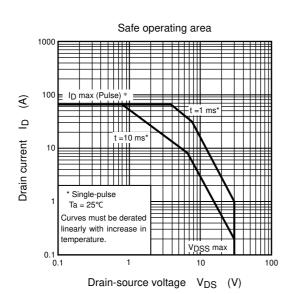


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